Unit: mm

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

## 2SC4409

# Power Amplifier Applications Power switching applications

- Low collector saturation voltage:  $V_{CE}$  (sat) = 0.5V (max) (at  $I_{C}$  = 1A)
- High speed switching time:  $t_{stg} = 500ns$  (typ.)
- Small flat package
- PC = 1~2 W (Mounted on a ceramic substrate)
- Complementary to 2SA1681

#### Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Collector-base voltage	$V_{CBO}$	80	V	
Collector-emitter voltage	V <sub>CEO</sub>	50	V	
Emitter-base voltage	$V_{EBO}$	6	V	
Collector current	IC	2	Α	
Base current	ΙΒ	0.2	Α	
Collector power dissipation	$P_{C}$	500	mW	
Collector power dissipation	P <sub>C</sub> (Note)	1000	mW	
Junction temperature	Tj	150	°C	
Storage temperature range	T <sub>stg</sub>	<b>−55~150</b>	°C	

Note: 2SC4409 mounted on a ceramic substrate (250  $\text{mm}^2 \times 0.8 \text{ t}$ )

1.6MAX. 4.6MAX 1.7MAX  $0.4 \pm 0.05$ + 0.08 0.4 - 0.05 + 0.08 0.4 - 0.05 1.5 ± 0.1 1.5 ± 0.1 1. Base 2. Collector (heat sink) 3. Emitter **JEDEC** JEITA SC-62 **TOSHIBA** 2-5K1A

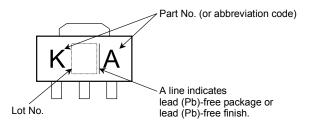
Weight: 0.05 g (typ.)



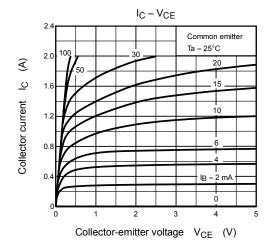
## Electrical Characteristics (Ta = 25°C)

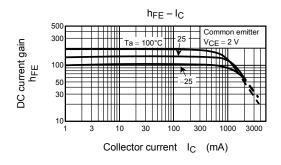
Cha	racteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off c	urrent	I <sub>CBO</sub>	$V_{CB} = 80 \text{ V}, I_{E} = 0$	_	_	0.1	μΑ
Emitter cut-off cur	rrent	I <sub>EBO</sub>	V <sub>EB</sub> = 6 V, I <sub>C</sub> = 0	_	_	0.1	μА
Collector-emitter	breakdown voltage	V (BR) CEO	$I_C = 10 \text{ mA}, I_B = 0$	50	_	_	V
DC current gain		h <sub>FE (1)</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 100 mA	120	_	400	
		h <sub>FE (2)</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 1.5 A	40	_	_	
Collector-emitter	saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = 1 A, I <sub>B</sub> = 0.05 A	_	_	0.5	V
Base-emitter satu	ration voltage	V <sub>BE (sat)</sub>	I <sub>C</sub> = 1 A, I <sub>B</sub> = 0.05 A	_	_	1.2	V
Transition frequer	псу	f <sub>T</sub>	V <sub>CE</sub> = 2 V, I <sub>C</sub> = 100 mA	_	100	_	MHz
Collector output of	apacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	14	_	pF
Switching time SI	Turn-on time	t <sub>on</sub>	Output $\begin{array}{c c} & & & & \\ & 20 \ \mu \text{s} & \text{Input} & & & \\ & & & & \\ & & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & & \\ & & \\ & & & \\ & \\ & & \\ & & \\ & & \\ & & \\ & & \\ & & \\ & & \\ & & \\ & & \\ & & \\ & & \\ & & \\ &$	_	0.1	_	
	Storage time	t <sub>stg</sub>		_	0.5	_	μS
	Fall time	t <sub>f</sub>		_	0.1	_	

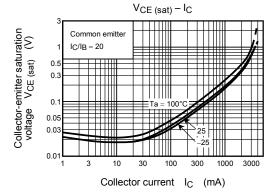
## Marking

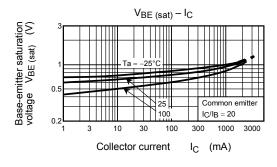


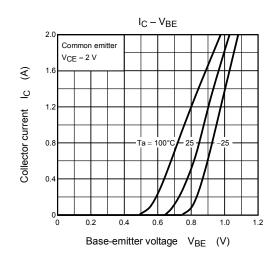
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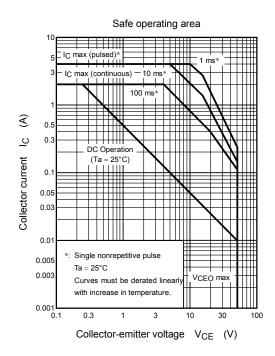












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